

## 100352

### Low Power 8-Bit Buffer with Cut-Off Drivers

#### General Description

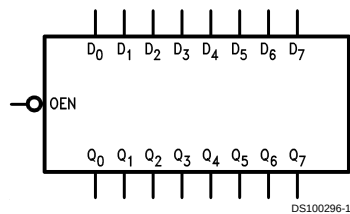
The 100352 contains an 8-bit buffer, individual inputs ( $D_n$ ), outputs ( $Q_n$ ), and a data output enable pin ( $\overline{OEN}$ ). A  $Q$  output follows its  $D$  input when the  $\overline{OEN}$  pin is LOW. A HIGH on  $\overline{OEN}$  holds the outputs in a cut-off state. The cut-off state is designed to be more negative than a normal ECL LOW level. This allows the output emitter-followers to turn off when the termination supply is  $-2.0V$ , presenting a high impedance to the data bus. This high impedance reduces termination power and prevents loss of low state noise margin when several loads share the bus.

The 100352 outputs are designed to drive a doubly terminated  $50\Omega$  transmission line ( $25\Omega$  load impedance). All inputs have  $50\text{ k}\Omega$  pull-down resistors.

#### Features

- Cut-off drivers
- Drives  $25\Omega$  load
- Low power operation
- 2000V ESD protection
- Voltage compensated operating range =  $-4.2V$  to  $-5.7V$
- Available to industrial grade temperature range
- Available to MIL-STD-883

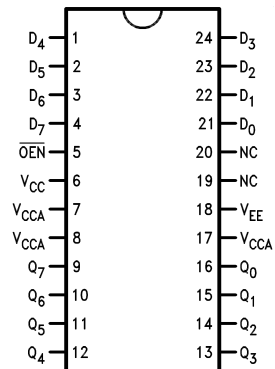
#### Logic Symbol



| Pin Names        | Description         |
|------------------|---------------------|
| $D_0$ – $D_7$    | Data Inputs         |
| $\overline{OEN}$ | Output Enable Input |
| $Q_0$ – $Q_7$    | Data Outputs        |
| NC               | No Connect          |

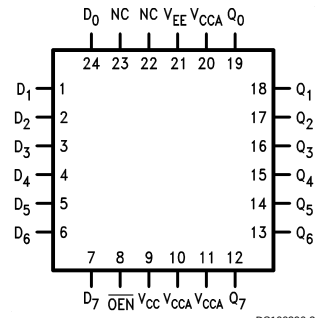
## Connection Diagrams

24-Pin DIP



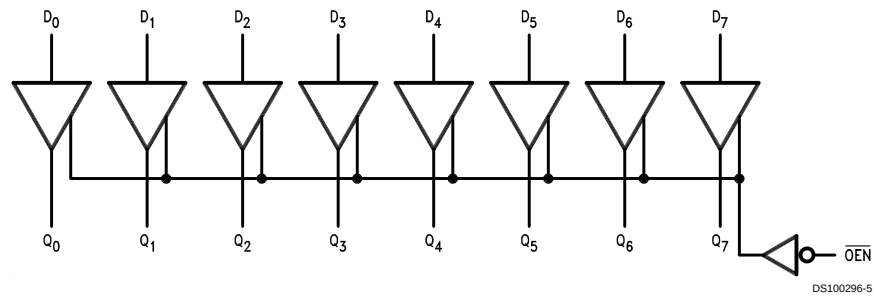
DS100296-2

24-Pin Quad Cerpak



DS100296-3

## Logic Diagram



## Truth Table

| Inputs |                  | Outputs |
|--------|------------------|---------|
| Dn     | $\overline{QEN}$ | Qn      |
| L      | L                | L       |
| H      | L                | H       |
| X      | H                | Cutoff  |

H = HIGH Voltage Level  
 L = LOW Voltage Level  
 Cutoff = Lower-than-LOW State  
 X = Don't Care

## Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Above which the useful life may be impaired

Storage Temperature ( $T_{STG}$ )  $-65^{\circ}\text{C}$  to  $+150^{\circ}\text{C}$

Maximum Junction Temperature ( $T_J$ )  
Ceramic  $+175^{\circ}\text{C}$

$V_{EE}$  Pin Potential to

Ground Pin  $-7.0\text{V}$  to  $+0.5\text{V}$

Input Voltage (DC)  $V_{EE}$  to  $+0.5\text{V}$

Output Current (DC Output HIGH)  $-100\text{ mA}$

ESD (Note 2)

$\geq 2000\text{V}$

## Recommended Operating Conditions

Case Temperature ( $T_C$ )

Military  $-55^{\circ}\text{C}$  to  $+125^{\circ}\text{C}$

Supply Voltage ( $V_{EE}$ )  $-5.7\text{V}$  to  $-4.2\text{V}$

**Note 1:** Absolute maximum ratings are those values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

**Note 2:** ESD testing conforms to MIL-STD-883, Method 3015.

## Military Version DC Electrical Characteristics

$V_{EE} = -4.2\text{V}$  to  $-5.7\text{V}$ ,  $V_{CC} = V_{CCA} = \text{GND}$ ,  $T_C = -55^{\circ}\text{C}$  to  $+125^{\circ}\text{C}$

| Symbol    | Parameter            | Min          | Max   | Units         | $T_C$                                           | Conditions                                                                                            | Notes                                                        |
|-----------|----------------------|--------------|-------|---------------|-------------------------------------------------|-------------------------------------------------------------------------------------------------------|--------------------------------------------------------------|
| $V_{OH}$  | Output HIGH Voltage  | -1025        | -870  | mV            | $0^{\circ}\text{C}$ to $+125^{\circ}\text{C}$   | $V_{IN} = V_{IH(\text{Max})}$<br>or $V_{IL(\text{Min})}$                                              | Loading with $25\Omega$ to $-2.0\text{V}$<br>(Notes 3, 4, 5) |
|           |                      | -1085        | -870  | mV            | $-55^{\circ}\text{C}$                           |                                                                                                       |                                                              |
| $V_{OL}$  | Output LOW Voltage   | -1830        | -1620 | mV            | $0^{\circ}\text{C}$ to $+125^{\circ}\text{C}$   | $V_{IN} = V_{IH(\text{Min})}$<br>or $V_{IL(\text{Max})}$                                              | Loading with $25\Omega$ to $-2.0\text{V}$<br>(Notes 3, 4, 5) |
|           |                      | -1830        | -1555 | mV            | $-55^{\circ}\text{C}$                           |                                                                                                       |                                                              |
| $V_{OHC}$ | Output HIGH Voltage  | -1035        |       | mV            | $0^{\circ}\text{C}$ to $+125^{\circ}\text{C}$   | $V_{IN} = V_{IH(\text{Min})}$<br>or $V_{IL(\text{Max})}$                                              | Loading with $25\Omega$ to $-2.0\text{V}$<br>(Notes 3, 4, 5) |
|           |                      | -1085        |       | mV            | $-55^{\circ}\text{C}$                           |                                                                                                       |                                                              |
| $V_{OLC}$ | Output LOW Voltage   |              | -1610 | mV            | $0^{\circ}\text{C}$ to $+125^{\circ}\text{C}$   | $V_{IN} = V_{IH(\text{Min})}$ , or $V_{IL(\text{Max})}$                                               | $\overline{\text{OEN}} = \text{HIGH}$<br>(Notes 3, 4, 5)     |
|           |                      |              | -1555 | mV            | $-55^{\circ}\text{C}$                           |                                                                                                       |                                                              |
| $V_{OLZ}$ | Cut-Off LOW Voltage  |              | -1950 | mV            | $0^{\circ}\text{C}$ to $+125^{\circ}\text{C}$   | $V_{IN} = V_{IH(\text{Min})}$ , or $V_{IL(\text{Max})}$                                               | $\overline{\text{OEN}} = \text{HIGH}$<br>(Notes 3, 4, 5)     |
|           |                      |              | -1850 | mV            | $-55^{\circ}\text{C}$                           |                                                                                                       |                                                              |
| $V_{IH}$  | Input HIGH Voltage   | -1165        | -870  | mV            | $-55^{\circ}\text{C}$ to $+125^{\circ}\text{C}$ | Guaranteed HIGH signal for All inputs                                                                 | 1, 2, 3, 4                                                   |
| $V_{IL}$  | Input LOW Voltage    | -1830        | -1475 | mV            | $-55^{\circ}\text{C}$ to $+125^{\circ}\text{C}$ | Guaranteed LOW signal for All inputs                                                                  | (Notes 3, 4, 5, 6)                                           |
| $I_{IL}$  | Input LOW Current    | 0.50         |       | $\mu\text{A}$ | $-55^{\circ}\text{C}$ to $+125^{\circ}\text{C}$ | $V_{EE} = 4.2\text{V}$<br>$V_{IN} = V_{IL(\text{Min})}$                                               | (Notes 3, 4, 5)                                              |
| $I_{IH}$  | Input HIGH Current   |              | 240   | $\mu\text{A}$ | $0^{\circ}\text{C}$ to $+125^{\circ}\text{C}$   | $V_{EE} = -5.7\text{V}$                                                                               | (Notes 3, 4, 5)                                              |
|           |                      |              | 340   | $\mu\text{A}$ | $-55^{\circ}\text{C}$                           | $V_{IN} = V_{IH(\text{Max})}$                                                                         |                                                              |
| $I_{EE}$  | Power Supply Current | -145<br>-150 | -55   | mA            | $-55^{\circ}\text{C}$ to $+125^{\circ}\text{C}$ | Inputs Open<br>$V_{EE} = -4.2\text{V}$ to $-4.8\text{V}$<br>$V_{EE} = -4.2\text{V}$ to $-5.7\text{V}$ | (Notes 3, 4, 5)                                              |

**Note 3:** F100K 300 Series cold temperature testing is performed by temperature soaking (to guarantee junction temperature equals  $-55^{\circ}\text{C}$ ), then testing immediately without allowing for the junction temperature to stabilize due to heat dissipation after power-up. This provides "cold start" specs which can be considered a worst case condition at cold temperatures.

**Note 4:** Screen tested 100% on each device at  $-55^{\circ}\text{C}$ ,  $+25^{\circ}\text{C}$ , and  $+125^{\circ}\text{C}$ , Subgroups 1, 2, 3, 7, and 8.

**Note 5:** Sample tested (Method 5005, Table I) on each manufactured lot at  $-55^{\circ}\text{C}$ ,  $+25^{\circ}\text{C}$ , and  $+125^{\circ}\text{C}$ , Subgroups A1, 2, 3, 7, and 8.

**Note 6:** Guaranteed by applying specified input condition and testing  $V_{OH}/V_{OL}$ .

## AC Electrical Characteristics

$V_{EE} = -4.2\text{V}$  to  $-5.7\text{V}$ ,  $V_{CC} = V_{CCA} = \text{GND}$

| Symbol    | Parameter                         | $T_C = -55^{\circ}\text{C}$ |      | $T_C = +25^{\circ}\text{C}$ |      | $T_C = +125^{\circ}\text{C}$ |      | Units | Conditions   | Notes                |
|-----------|-----------------------------------|-----------------------------|------|-----------------------------|------|------------------------------|------|-------|--------------|----------------------|
|           |                                   | Min                         | Max  | Min                         | Max  | Min                          | Max  |       |              |                      |
| $t_{PLH}$ | Propagation Delay                 | 0.30                        | 2.60 | 0.50                        | 2.40 | 0.50                         | 2.70 | ns    | Figures 1, 2 | (Notes 7, 8, 10, 11) |
| $t_{PHL}$ | Dn to Output                      |                             |      |                             |      |                              |      |       |              |                      |
| $t_{PZH}$ | Propagation Delay                 | 1.20                        | 4.40 | 1.40                        | 4.20 | 1.20                         | 4.40 | ns    | Figures 1, 2 | (Notes 7, 8, 9, 11)  |
| $t_{PHZ}$ | $\overline{\text{OEN}}$ to Output | 0.70                        | 3.00 | 0.70                        | 2.80 | 0.70                         | 3.20 |       |              |                      |

## AC Electrical Characteristics (Continued)

$V_{EE} = -4.2V$  to  $-5.7V$ ,  $V_{CC} = V_{CCA} = GND$

| Symbol    | Parameter              | $T_C = -55^\circ C$ |      | $T_C = +25^\circ C$ |      | $T_C = +125^\circ C$ |      | Units | Conditions   | Notes     |
|-----------|------------------------|---------------------|------|---------------------|------|----------------------|------|-------|--------------|-----------|
|           |                        | Min                 | Max  | Min                 | Max  | Min                  | Max  |       |              |           |
| $t_{TLH}$ | Transition Time        | 0.40                | 2.50 | 0.40                | 2.40 | 0.40                 | 2.70 | ns    | Figures 1, 2 | (Note 10) |
| $t_{THL}$ | 20% to 80%, 80% to 20% |                     |      |                     |      |                      |      |       |              |           |

**Note 7:** F100K 300 Series cold temperature testing is performed by temperature soaking (to guarantee junction temperature equals  $-55^\circ C$ ), then testing immediately after power-up. This provides "cold start" specs which can be considered a worst case condition at cold temperatures.

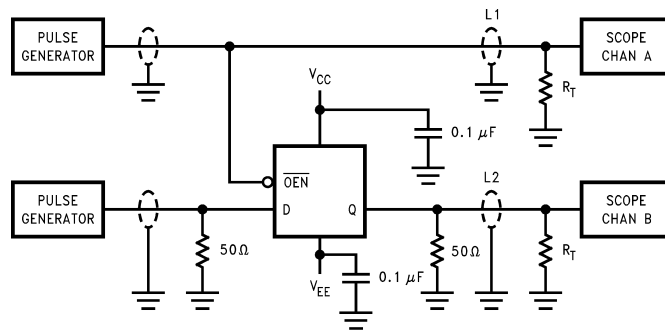
**Note 8:** Screen tested 100% on each device at  $+25^\circ C$  temperature only, Subgroup A9.

**Note 9:** Sample tested (Method 5005, Table I) on each manufactured lot at  $+25^\circ C$ , Subgroup A9, and at  $+125^\circ C$  and  $-55^\circ C$  temperatures, Subgroups A10 and A11.

**Note 10:** Not tested at  $+25^\circ C$ ,  $+125^\circ C$ , and  $-55^\circ C$  temperature (design characterization data).

**Note 11:** The propagation delay specified is for single output switching. Delays may vary up to 300 ps with multiple outputs switching.

## Test Circuitry



### Notes:

$V_{CC}, V_{CCA} = +2V$ ,  $V_{EE} = -2.5V$

$L1$  and  $L2$  = equal length 50 ohm impedance lines

$R_T = 50\Omega$  terminator internal to scope

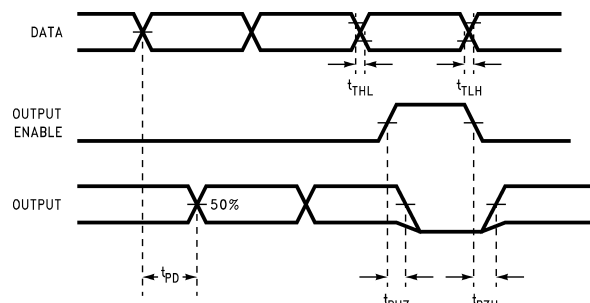
Decoupling 0.1  $\mu F$  from GND to  $V_{CC}$  and  $V_{EE}$

All unused outputs are loaded with 25 ohm to GND

$C_L$  = Fixture and stray capacitance  $\leq 3$  pF

FIGURE 1. AC Test Circuit

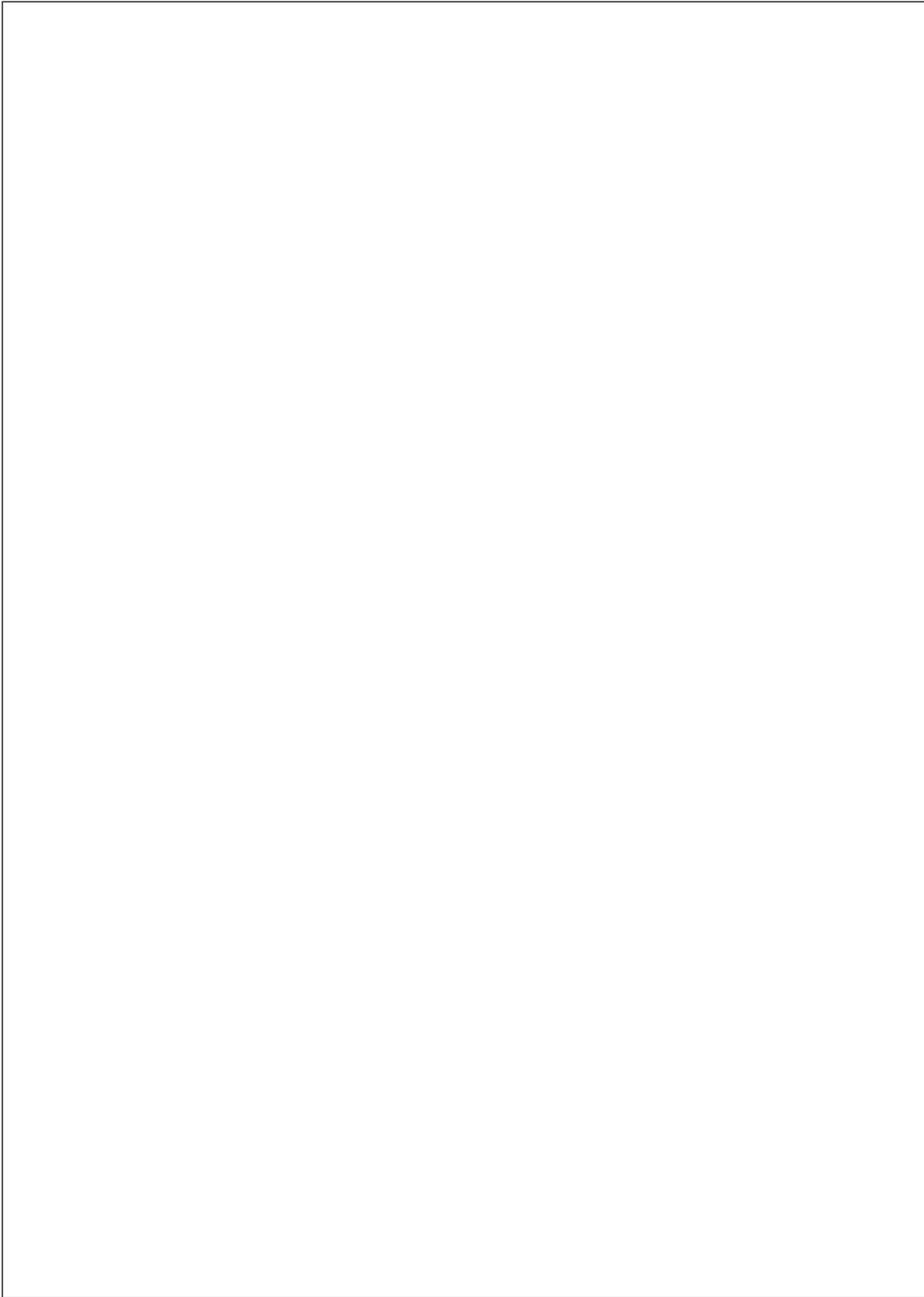
## Switching Waveforms



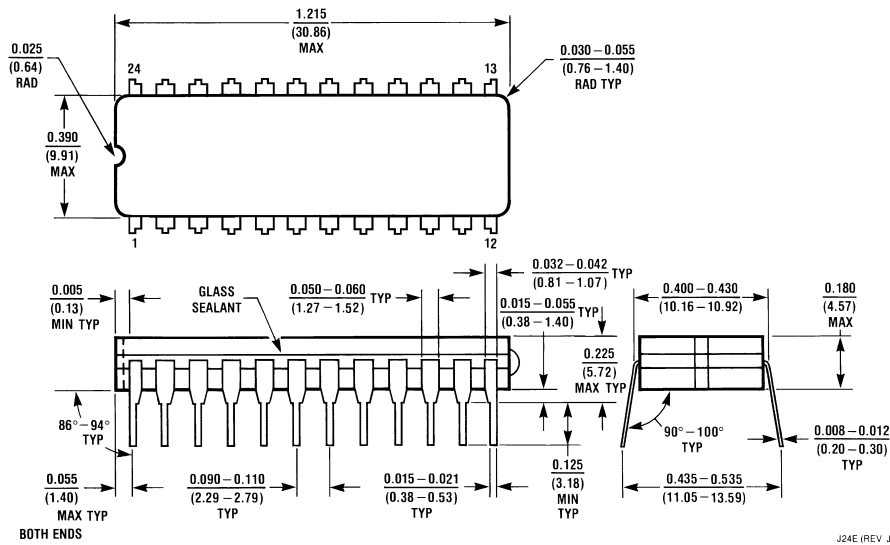
### Note:

The output AC measurement point for cut-off propagation delay testing = the 50% voltage point between active  $V_{OL}$  and  $V_{OH}$ .

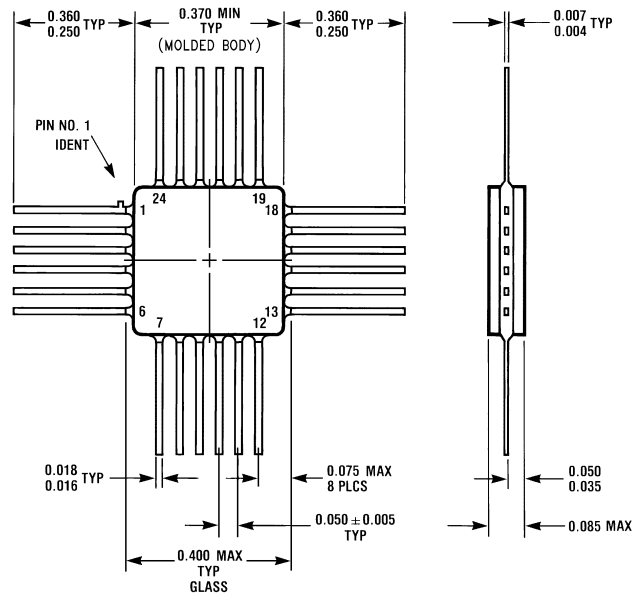
FIGURE 2. Propagation Delay, Cut-Off and Transition Times



# Physical Dimensions inches (millimeters) unless otherwise noted



**24-Lead Ceramic Dual-In-Line Package (0.400" Wide) (D)**  
NS Package Number J24E



**24-Lead Quad Cerpak (F)**  
NS Package Number W24B

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Tel: 1-800-272-9959  
Fax: 1-800-737-7018  
Email: support@nsc.com

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**National Semiconductor Europe**

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105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: [info@moschip.ru](mailto:info@moschip.ru)

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